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# Recent strategies for activating the basal planes of transition metal dichalcogenides towards hydrogen production 

Hang Xia, $\dagger^{\text {a }}$ Zude Shi, $\uparrow^{a}$ Chengshi Gong ${ }^{\text {ab }}$ and Yongmin He (iD)*a


#### Abstract

The hydrogen evolution reaction (HER) presents an environmentally friendly, efficient, and cost-effective way to produce hydrogen fuel. Recently, two-dimensional (2D) transition metal dichalcogenides (TMDCs) have emerged as a fascinating class of HER materials. Their atomically thin nature acts as an interface with the possibility of maximum exposure of nearly all active sites to the reaction environment. However, for most non-metallic TMDCs, as exemplified by $2 \mathrm{H}-\mathrm{MoS}_{2}, 1 \mathrm{~T}-\mathrm{PtSe}_{2}$, and $1 \mathrm{~T}^{\prime}-\mathrm{ReSe}_{2}$, their basal planes are usually HER-inert except for minor edges. Based on their rich chemistry, significant progress has been recently made to activate the basal planes for HER. This review provides an overview of the current activating strategies. They can be classified into internal and external regulations, depending on whether the pristine structure is altered or not. The former directly creates more active sites through doping, vacancies, phases, grain boundaries (GBs), and superlattices. On the other hand, the latter indirectly promotes the activity utilizing external methods such as the electric field, strain, substrates, and heterostructures. We discuss each strategy's principles and characteristics and highlight their enhanced catalytic activities. We finally provide personal perspectives on the challenges and opportunities in this emerging field, including a joint strategy, a phase-engineering strategy, electricalelectrocatalytic coupling, as well as the potential of "single-atom-layer" catalysis.


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## 1. Introduction

Exploring clean and renewable alternative energy technology is highly desirable to alleviate global warming and the environmental degradation caused by the excessive use of nonrenewable fossil fuels. ${ }^{1,2}$ Electrochemical water splitting that converts electrical energy into hydrogen energy through the hydrogen evolution reaction (HER) is considered a promising green energy technology, exhibiting high energy density, environmental friendliness, and high product purity. ${ }^{3,4}$ Platinum


Hang Xia received his B.S. degree in 2019 from Central South University. He is currently a PhD candidate in physical chemistry at Hunan University under the supervision of Professor Yongmin He. His research focuses on micro/nano electrocatalysis for water splitting.

Zude Shi received his M.S. degree in 2021 from Lanzhou University and his B.S. degree in 2018 from the same university. Subsequently, he joined the Yongmin He group at the College of Chemistry and Chemical Engineering, Hunan University, China. His research focuses on the surface and interface electrocatalysis of lowdimensional materials.
(Pt) and other noble metal-based electrocatalysts give superior performance for HER; ;-8 however, their scarcity and poor durability seriously hinder their large-scale application towards hydrogen production. ${ }^{9-11}$ Therefore, exploring cheap and efficient HER catalysts as an alternative to noble metals has attracted growing attention. In particular, two-dimensional (2D) transition metal dichalcogenides (TMDCs), represented by $\mathrm{MoS}_{2}$, are widely favored due to their low cost, layered structures, and fascinating electronic properties. ${ }^{12-14}$ To date, substantial research efforts have been devoted to developing highly efficient HER catalysts based on 2D TMDCs. The key advantage is that their atomically thin nature can act as an interface with the possibility of maximum exposure of nearly all active sites to the reaction environment. ${ }^{15-17}$

For a structural point of view, 2D TMDC materials are configured by $\mathrm{X}-\mathrm{M}-\mathrm{X}$ layers ( M : transition metal, and X: chalcogen), ${ }^{18}$ in which M atoms are sandwiched by two X -atom planes. They have stronger ionic-covalent bonds between M and X atoms in the planes, with weaker van der Waals (vdW) interactions out of the planes. There are two primary structures in a TMDC layer: the basal plane and the edge. Both experiments and theory prove that the basal planes of most nonmetallic TMDCs, for example, $2 \mathrm{H}-\mathrm{MoS}_{2}, 1 \mathrm{~T}-\mathrm{PtSe}_{2}$, and $1 \mathrm{~T}^{\prime}-$ $\mathrm{ReSe}_{2}$, are usually catalytically inert in HER, in sharp contrast to the HER-active edges. ${ }^{19-24}$ Considering the extremely large area in a TMDC layer (close to $100 \%$ ), ${ }^{25,26}$ activating the inert basal planes presents a promising strategy to improving the overall catalytic activity of a whole layer (Fig. 1). ${ }^{27}$ The most intuitive example is that when edge-active $2 \mathrm{H}-\mathrm{MoS}_{2}$ undergoes a phase transition into basal-plane-active $1 \mathrm{~T}-\mathrm{MoS}_{2}$, the catalytic activity is improved by orders of magnitude. ${ }^{28-31}$ Recently, significant progress has been made to activate the basal plane for HER. For example, the HER activity of the $\mathrm{MoS}_{2}$ basal plane is remarkably boosted by introducing strained vacancies, and its Tafel slope is decreased from $98 \mathrm{mV} \mathrm{dec}{ }^{-1}$ to $60 \mathrm{mV} \mathrm{dec}{ }^{-1} .{ }^{32}$ In another example, an onset potential of -25 mV and Tafel slope of 54 mV $\mathrm{dec}^{-1}$ were achieved by activating the $\mathrm{MoS}_{2}$ basal plane with ultra-high-density grain boundaries (GBs). ${ }^{33}$ Based on current
achievements, it is time to offer a critical review of this topic, potentially arousing a wide range of readers for the future development of this field. Note that some excellent reviews have already been published based on 2D TMDCs for HER, ${ }^{31,34-39}$ while there is still a lack of summaries focusing only on the basal plane and its activating strategies for HER.

Herein, we summarize currently-developed activating strategies on TMDC basal planes toward hydrogen production (Fig. 2), discuss their principles, and highlight their advantages as well. In brief, we first introduce the HER mechanism in acidic and basic media, emphasizing the critical pH -dependent role of the free energy of hydrogen adsorption $\left(\Delta G_{\mathrm{H}^{*}}\right)$ in the HER process. Then, we classify the strategies into internal or external regulations based on whether the pristine structure has been changed or not. The former is to directly create more active sites in the basal plane, including doping, vacancies, phases, GBs, and superlattices. The latter is to indirectly improve the basalplane activity through external methods, such as the electric field, strain, substrates, and heterostructures. The underlying principles and characteristics are discussed, and each method presents several representative examples. Finally, we provided personal perspectives on the challenges and opportunities of activating TMDC basal planes to develop high-efficient HER catalysts.

## 2. HER principle and Gibbs free energy of hydrogen adsorption

There are two possible reaction pathways in the HER process: Volmer-Tafel and Volmer-Heyrovsky mechanisms. ${ }^{47}$ Taking the acidic electrolyte as a typical example (Fig. 3a), in the first Volmer step (eqn (1)), the proton obtains an electron on the electrode material (M) surface to generate an adsorbed hydrogen atom $\left(\mathrm{H}_{\mathrm{ad}}\right)$ under the applied external potential. The $\mathrm{H}_{2}$ products will be generated by the following Tafel step or the Heyrovsky step. In detail, in the Tafel reaction, two neighboring $\mathrm{H}_{\mathrm{ad}}$ combined on the surface of the electrode to form $\mathrm{H}_{2}$ (eqn (2)). In contrast, in the Heyrovsky reaction, another proton gets


Dr. Chengshi Gong is an associate professor at Lanzhou City University (China) andis also a visiting scholar in Prof. Yongmin He's research group at Hunan University. Dr. Gong received his PhD Degree in 2014 from Lanzhou University. His research focuses on the preparation of two-dimensional materials and their applications in water splitting.


Dr. Yongmin He is a professor at the College of Chemistry and Chemical Engineering at Hunan University (China). Dr. He obtained his PhD Degree at Lanzhou University in 2015 (China), and later worked in Prof. Zheng Liu and Prof. Qi Jie Wang's groups as a postdoc research fellow (2015-2021) at Nanyang Technological University (Singapore). His research interest focuses on the synthesis and structure-engineering of atom-thin materials, and their electronic or on-chip electrochemical devices, with various applications in nanoelectronics, iontronics, sensors, and electrocatalysis.



Fig. 1 Activating basal planes of two-dimensional (2D) transition metal dichalcogenides (TMDCs). Top: illustration of the activating strategy of the basal planes. Bottom: volcano plot of the exchange current density as a function of the free energy of hydrogen adsorption ( $\Delta G_{H^{*}}$ ) for the original basal planes and the activated ones. Data obtained from ref. 10,19,22,32,40-46 Abbreviations: V-MoS for vacancy-MoS $_{2}, \mathrm{SV}-\mathrm{MoS} 2$ for strained-sulfur vacancy $\mathrm{MoS}_{2}, ~ W S S e ~ V_{s}$ for the $S$ vacancy of WSSe, WSSe $V_{\text {se }}$ for the Se vacancy of WSSe, EC for the electric field, and $V$ SAC $@ 1 T$ $\mathrm{WS}_{2}$ for single-site vanadium substitution in $1 \mathrm{~T}-\mathrm{WS}_{2}$.
close to the $\mathrm{H}_{\mathrm{ad}}$ and then receives a new electron to generate $\mathrm{H}_{2}$ (eqn (3)).

$$
\begin{equation*}
\text { Volmer step: } \mathrm{H}_{3} \mathrm{O}^{+}+\mathrm{M}+\mathrm{e}^{-} \rightarrow \mathrm{M}-\mathrm{H}_{\mathrm{ad}}+\mathrm{H}_{2} \mathrm{O} \tag{1}
\end{equation*}
$$

$$
\begin{equation*}
\text { Tafel step: } 2 \mathrm{M}-\mathrm{H}_{\mathrm{ad}} \rightarrow \mathrm{H}_{2}+2 \mathrm{M} \tag{2}
\end{equation*}
$$

Heyrovsky step: $\mathrm{H}_{3} \mathrm{O}^{+}+\mathrm{M}-\mathrm{H}_{\mathrm{ad}}+\mathrm{e}^{-} \rightarrow \mathrm{H}_{2}+\mathrm{M}+\mathrm{H}_{2} \mathrm{O}$

No matter, which pathway HER undergoes, the adsorption of hydrogen atoms is a crucial factor. Generally, $\Delta G_{\mathrm{H}^{*}}$ is recognized as an essential parameter for evaluating the HER performance, and the best HER catalysts possess $\Delta G_{\mathrm{H}^{*}} \sim 0{ }^{48}$ If $\Delta G_{\mathrm{H}^{*}}$ is too negative, the conversation and desorption processes will be hindered, easily making the catalyst to be poisoned. On the other hand, a much-positive $\Delta G_{\mathrm{H}^{*}}$ will weaken the adsorption, leading to inadequate H atoms in the catalytic reaction. A volcano plot is usually used to describe the relationship between $\Delta G_{\mathrm{H}^{*}}$ and the exchange current density for HER catalysts (Fig. 1). It can be seen that the $2 \mathrm{H}-\mathrm{MoS}_{2}$ basal plane, located at the right region of the volcano plots, has a poor H adsorption ability, and its rate-limiting step is the first Volmer step. ${ }^{22}$ Once the basal planes of TMDCs are activated to obtain a trade-off between adsorption and desorption, they will be consequently located in the near-central region of the volcano plots.

Notably, both, Volmer-Tafel and Volmer-Heyrovsky's steps are strongly pH -dependent. Distinct from acidic solutions with
sufficient hydronium cations $\left(\mathrm{H}_{3} \mathrm{O}^{+}\right)$as protons, the proton source in the basic medium (alkaline or neutral) is $\mathrm{H}^{+}$, generated from the water dissociation (Fig. 3b and eqn (4)). ${ }^{49}$ As a result, the proton source in basic media is usually limited, and thus leads to a tardy HER rate compared to an acidic solution. ${ }^{35}$ Next, for the Tafel step, two $\mathrm{H}_{\mathrm{ad}}$ directly combined to generate $\mathrm{H}_{2}$ (eqn (5)). For the Heyrovsky step, the $\mathrm{H}_{\mathrm{ad}}$ would react with $\mathrm{H}_{2} \mathrm{O}$ and then yields $\mathrm{H}_{2}$ and $\mathrm{OH}^{-}$(eqn (6)). Note that, except for the above steps, the expense of the water molecules near the electrode surface (that is, lowering the water concentration in the electrical double layer) could push the balance of the waterinvolved reaction (eqn (4) and (6)) in the reverse direction. ${ }^{50}$ This phenomenon will further lower the HER rate in the basic medium, on the other hand. Therefore, the rational design of the electrocatalysts with excellent hydrogen adsorption and water dissociation is a vital direction. ${ }^{51}$

$$
\begin{gather*}
\text { Volmer step: } \mathrm{H}_{2} \mathrm{O}+\mathrm{M}+\mathrm{e}^{-} \rightarrow \mathrm{M}-\mathrm{H}_{\mathrm{ad}}+\mathrm{OH}^{-}  \tag{4}\\
\text {Tafel step: } 2 \mathrm{M}-\mathrm{H}_{\mathrm{ad}} \rightarrow \mathrm{H}_{2}+2 \mathrm{M} \tag{5}
\end{gather*}
$$

Heyrovsky step: $\mathrm{H}_{2} \mathrm{O}+\mathrm{M}-\mathrm{H}_{\mathrm{ad}}+\mathrm{e}^{-} \rightarrow \mathrm{H}_{2}+\mathrm{OH}^{-}+\mathrm{M}$

## 3. Internal regulation

This section highlights the recent advances in the internal structural regulation of TMDC's basal planes by engineering


Fig. 2 Overview of the currently-developed strategies for activating TMDC basal planes for the hydrogen evolution reaction (HER). The strategies are divided into internal and external regulation, depending on whether the pristine structure is altered or not. The former is inclined to directly create more active structures, including doping, vacancies, phases, GBs, and superlattices. The latter indirectly promotes the activity of the basal planes by external methods, such as the electric field, strain, substrates, and heterostructures.
their atomic structures, such as metal/nonmetal-doping, vacancies, phases, GBs, and superlattices. These structures would act as the critical active sites in basal planes for HER.

### 3.1 Doping strategy

3.1.1 Metal-doping of TMDCs. Metal-doping has been widely adopted to activate the basal plane of TMDCs in the HER. Currently, a large number of methods enable effective doping, for example, chemical vapor deposition (CVD), ${ }^{52-54}$ solvothermal method, ${ }^{55,56}$ electrochemical depositions, ${ }^{57,58}$ plasma, ${ }^{59,60}$ photoreductions, ${ }^{61}$ and self-assembly solution impregnation. ${ }^{62}$ According to the atomic structures of the doped metal atoms, this strategy presents two types: substitutional and interstitial doping, as shown in Fig. 4a. For substitutional doping, a large number of transition metals have been reported in TMDCs, such as Co, Fe, V, Cr, Pd, and Re. ${ }^{63,64}$ In theory, Tsai et al. used density functional theory (DFT) to calculate the $\Delta G_{\mathrm{H}^{*}}$ on different species of transition metal-doped $\mathrm{MoS}_{2}$, providing a rational design of a new $\mathrm{MoS}_{2}$-type catalyst to strengthen or weaken the binding of key intermediates (Fig. 4b). ${ }^{55,65,66}$ However, it was found in the experiments that this doping not only affects the bond strength on doped metal atoms, but also significantly alters their coordination environment that generally introduces SV and local phase transitions of the TMDC
catalysts. ${ }^{64}$ For example, Zhou et al. used the CVD approach to make two configurations of metal-doped $\mathrm{MoS}_{2}$ structures. ${ }^{67}$ As shown in Fig. 4c, Fe and Co-based configuration is usually accompanied by the generation of vacancies. Those obtained configurations can greatly improve the HER performance ( $3 \mathrm{Co}_{\mathrm{Mo}}-V_{\mathrm{s}}$ have the highest performances: a low overpotential at the current density of $10 \mathrm{~mA} \mathrm{~cm}{ }^{-2}\left(\eta_{10}=75 \mathrm{mV} v \mathrm{~s}\right.$. RHE), a Tafel slope of $57 \mathrm{mV} \mathrm{dec}{ }^{-1}$, and long-term durability ( $\eta_{10}$ drops by only 10 mV after 1000 cycles)), as shown in Fig. 4d. Similarly, Luo and co-workers obtained substitutional doping of Pd in the $\mathrm{MoS}_{2}$ basal plane using a solvothermal method, in which SVs were simultaneously introduced to trigger a local phase transition (Fig. 4e). It turned out to be an excellent HER performance approaching $\mathrm{Pt} / \mathrm{C}$ catalysts $\left(1 \% \mathrm{Pd}-\mathrm{MoS}_{2}\right.$ has an exchange current density of $805 \mu \mathrm{~A} \mathrm{~cm}{ }^{-2}$ and a $\eta_{10}$ of 78 mV in Fig. 4f). ${ }^{62}$ Further, these substituted catalysts with large coordination numbers show excellent structural stability.

On the other hand, interstitial doping, different from the above-mentioned substitution, is located atop the basal plane instead of being confined within the crystal lattice. Currently, $\mathrm{Pt}, \mathrm{Rh}, \mathrm{Pb}, \mathrm{Bi}, \mathrm{Pd}, \mathrm{Sn}, \mathrm{Nb}, \mathrm{Mo}$, and $\mathrm{Cu}^{54,57-59}$ have been used as interstitial dopant atoms in TMDCs for HER. For example, Shi and co-workers obtained a variety of atomically dispersed Pt , $\mathrm{Rh}, \mathrm{Cu}, \mathrm{Pb}, \mathrm{Bi}$, and Sn atoms on the $\mathrm{MoS}_{2}$ surface using an


Fig. 3 HER mechanism on a TMDC surface in different electrolytes: (a) acidic solution, (b) alkaline or neutral solution. Hydronium cation ( $\mathrm{H}_{3} \mathrm{O}^{+}$) and a water molecule $\left(\mathrm{H}_{2} \mathrm{O}\right)$ serve as proton donors in the acidic and basic electrolytes, respectively.
electrochemical underpotential deposition (Fig. 4g). ${ }^{56,58}$ Later, Yang and co-workers reported interstitial doped $2 \mathrm{H}-\mathrm{Nb}_{1.35} \mathrm{~S}_{2}$ using a CVD method, which delivered an exceptionally-high current density in HER $\left(1000 \mathrm{~mA} \mathrm{~cm}{ }^{-2}\right.$ at $\sim 370 \mathrm{mV}$ and 5000 $\mathrm{mA} \mathrm{cm}{ }^{-2}$ at $\left.\sim 420 \mathrm{mV}\right) .{ }^{54}$ In addition to the above heteroatom doping, Luo et al. used a cold hydrogen plasma method to synthesize Mo-single-atom doped $\mathrm{MoS}_{2}$ (homo-atom doping), achieving an enhancement of HER activity with a Tafel slope of $36.4 \mathrm{mV} \mathrm{dec}^{-1}$ and a high current density of $400 \mathrm{~mA} \mathrm{~cm}{ }^{-2}$ at $\sim 260 \mathrm{mV}$, as a result of the increase of hydrogen bond strength through hybridization in Fig. 4h. ${ }^{59}$
3.1.2 Nonmetal-doping of TMDCs. It is compelling to see that many workers ${ }^{59,68-70}$ have also employed various nonmetallic doping of TMDCs to activate their basal planes, such as $\mathrm{Se},{ }^{71} \mathrm{P},{ }^{72} \mathrm{~B},{ }^{73} \mathrm{~F},{ }^{74}$ and $\mathrm{N}^{75}$ doping. In 2017, Zhao et al. comprehensively examined the effect and changes in the band structure of various non-metal doped TMDCs, ${ }^{76}$ theoretically providing a suitable non-metallic element for HER (Fig. 5a). Later, Pető and co-workers found that the monolayer $\mathrm{MoS}_{2}$ exposed to the ambient atmosphere at room temperature would undergo an irreversible oxygen-substitution reaction. The oxygen atoms would be dropped into the basal plane to improve the HER performance (Fig. 5b and c). ${ }^{77}$ It was also observed that oxygen doping could facilitate expanding the interlayer distance and promote the transfer of protons. ${ }^{78}$ In addition to oxygen doping, Zang and co-workers also synthesized carbon (C)-doped $\mathrm{MoS}_{2}$ (Fig. 5d), which turned out to have low overpotential in an alkaline solution, close to that of the commercial $\mathrm{Pt} / \mathrm{C}$. The reason is the C-introduced orbital modulation effect, which
generates empty 2 p orbitals perpendicular to the basal plane, thus facilitating the adsorption and dissociation of water in alkaline solution, as shown in Fig. 5e. ${ }^{79}$ Xiao et al. fabricated nitrogen ( N )-doped $\mathrm{MoS}_{2}$ using one-step sintering method, which presents a low onset overpotential of 35 mV and Tafel slope of $41 \mathrm{mV} \mathrm{dec}{ }^{-1}$. Those N dopants in $\mathrm{MoS}_{2}$ could extremely increase the number of active sites toward HER and enhance the conductivity of the catalysts as well (Fig. 5g). ${ }^{75}$ Interestingly, Janus TMDC materials (MXY, $\mathrm{M}=$ transition metal, $\mathrm{X} / \mathrm{Y}=\mathrm{S}, \mathrm{Se}$, or Te , and $\mathrm{X} \neq \mathrm{Y})^{80}$ were also reported (Fig. 5f). ${ }^{81}$ They gave a better HER performance than the pristine ones, originating from the synergistic effect between the intrinsic defects and inherent structural strain in a Janus structure. ${ }^{82}$

Benefiting from the abundant valence states and flexible oxidation capabilities of these non-metal atoms, their doping method can finely modulate the electronic structure of TMDCs and accelerate and stabilize the HER process. Notably, the codoping of metals and non-metals has also been tried, which improves the intrinsic performance and increases catalytic sites by alloying and synergy at different sites. ${ }^{67}$ As a whole, nonmetal doping offers great potential to trigger more TMDCsbased catalyst reconstruction and optimize the reaction pathways.

### 3.2 Vacancy strategy

Vacancies are the commonly-found structures in TMDCs. Their distribution (isolated vacancies, di-sulfur vacancies, pair vacancies, cluster vacancies, etc.), concentration, and species ${ }^{83}$


Fig. 4 Metal-doping strategy of 2D-TMDCs for HER. (a) Schematic illustration of the substitutional (left) and interstitial (right) metal-doping in TMDCs. (b) Range of $\Delta G_{H^{*}}$ on each transition metal-doped $\mathrm{MoS}_{2}$. Reproduced with permission, ${ }^{65}$ Royal Society of Chemistry. (c) Two configurations of metal-doped $\mathrm{MoS}_{2}$ structures, in which the sulfur vacancies ( SV s) are marked in blue circles and the H -bonded S atoms in red circles. (d) The corresponding $\eta_{10}$-Tafel slope in $0.5 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ for the HER catalysts in (c). Reproduced with permission, ${ }^{67}$ Springer Nature. Substitutional doping of Pd in the $\mathrm{MoS}_{2}$ basal plane (e) and the polarization curves of the resultant catalysts (f). Reproduced with permission, ${ }^{62}$ Springer Nature. (g) Schematic illustration of the single-atom doping on the TMDC surfaces through an electrochemical deposition method. Reproduced with permission, ${ }^{57}$ Springer Nature. (h) Schematic illustration of interstitial Mo atom doping on $\mathrm{MoS}_{2}$ using a cold hydrogen-plasma method. Reproduced with permission, ${ }^{59}$ American Chemical Society
are crucial to improving the HER-activity of the basal plane. ${ }^{13,70,84,85}$ Currently, a variety of vacancy-engineering strategies, such as Ar plasma treatment, ${ }^{32}$ electron/ion beam/laser irradiation, ${ }^{86}$ strain (physical etching), ${ }^{87}$ solvothermal growth, ${ }^{88}$ CVD annealing, ${ }^{83}$ and electrochemical desulfurization (chemical etching) ${ }^{89}$ have been developed. Those vacancies can be divided into transition metal vacancies and chalcogenide vacancies in TMDCs, as shown in Fig. 6a.

To investigate the influences of structures and concentrations of chalcogenide vacancies on the basal plane for HER;

Zhang and co-workers employed mild $\mathrm{H}_{2}$ annealing to precisely create SVs in the monolayer $\mathrm{MoS}_{2}$ at different temperatures and achieved isolated, paired, and clustered SVs (Fig. 6b). In another example, Tsai et al. used electrochemical desulfurization to introduce SV in the basal plane of the monolayer $\mathrm{MoS}_{2}$ with a concentration of 21.9 at\% (Fig. 6c). Combining the DFT calculations (Fig. 6d), the authors demonstrated that only isolated atomic vacancies can be considered localized states to maximize the charge hopping probability, and thus significantly increase the turnover frequency of Mo atoms $\left(\mathrm{TOF}_{\mathrm{Mo}}=\right.$


Fig. 5 Nonmetal-doping strategy of 2D-TMDCs for HER. (a) The calculated $E_{\text {CBM }}$ and $E_{V B M}$ of pristine and nonmetal-doped MoSe 2 monolayers. Reproduced with permission, ${ }^{76}$ Springer Nature. (b) Atomic structure (left) and scanning tunneling microscopy (STM) images (right) of the exfoliated $\mathrm{MoS}_{2}$ monolayer in the air after one month, and its corresponding HER performance (c). Reproduced with permission," Springer Nature. Schematic illustration of carbon (C)-doped $\mathrm{MoS}_{2}$ (d) and its corresponding HER performance in an alkaline electrolyte (e). Reproduced with permission, ${ }^{79}$ Springer Nature. (f) Janus $\mathrm{MoS}_{2}$ monolayer synthesized through a plasma-enhanced CVD method. Reproduced with permission, ${ }^{81}$ Springer Nature. (g) Polarization curves of nitrogen ( N )-doped $\mathrm{MoS}_{2}$ samples. Reproduced with permission, ${ }^{75}$ Wiley-VCH.
$10 \mathrm{~s}^{-1}$ ) of samples (Fig. 6e). ${ }^{83,89}$ Nevertheless, they also observed that a further increase in the vacancy density would form clustered SVs, which could produce deep trapping levels to lower the electronic properties, consequently degrading HER performance. To improve the vacancy density, both Lei Li and Xin Wang et al. created much higher concentrations of SVs in $\mathrm{MoS}_{2}$ compared to the above studies. They impressively found that the unsaturated Mo atoms acted as the active sites, which could introduce gap states favorable for hydrogen bonding, leading to an excellent per-site turnover frequency $\left(1000 \mathrm{~s}^{-1}\right.$ and $10000 \mathrm{~s}^{-1}$ corresponding to the overpotentials of 200 mV and 300 mV in their work). ${ }^{88,90}$

On the other hand, compared with the above non-metal vacancies, Yang et al. showed that a large number of Mo vacancies were formed in CVD-grown $\mathrm{MoS}_{2}$ after Helium ion irradiation, while they found a lower HER activity (Fig. 6f and g). ${ }^{86}$ This phenomenon can be explained by the fact that the physical etching could severely damage the atomic structures of

TMDC's basal planes, such as holes, cracks, and curl zones and degrade their electronic properties. Note that these non-metal vacancies would play a more positive role in improving the HER performance, as compared to the metal ones.

### 3.3 GB strategy

Recent studies have demonstrated that GBs possess a high catalytic activity due to the synergistic effect raised from the local strain and unsaturated sites. ${ }^{91}$ Different from the above doping and vacancies, GB is a type of 1 D defect (besides edge), with dreidel-shaped dislocation cores and ringed motifs. ${ }^{70,85}$ They can be divided into homo-phase and hetero-phase structures according to their neighboring phases, as shown in Fig. 7a. The main approaches to synthesizing GBs consist of CVD, ${ }^{92,93}$ molecular beam epitaxy (MBE), ${ }^{94}$ physical vapor deposition (PVD), ${ }^{95,96}$ metalorganic chemical vapor deposition (MOCVD), ${ }^{97,98}$ hydrothermal methods, ${ }^{99}$ and plasma. ${ }^{93}$ Additionally, other factors such as the fast kinetic processes, the multiplicity of phases and ingredients,


Fig. 6 Vacancy strategy of 2D-TMDCs for HER. (a) Schematic illustration of two kinds of vacancies in TMDCs: transition metal vacancy (left) and chalcogenide vacancy (right). (b) Scanning transmission electron microscopy (STEM) images of the isolated S, paired S, and clustered S vacancies in a $\mathrm{MoS}_{2}$ monolayer generated by varied $\mathrm{H}_{2}$-annealing conditions. Reproduced with permission, ${ }^{83} \mathrm{Wiley-VCH}$. (c) Schematic illustration of the optimized structures of $\mathrm{MoS}_{2}$ with varied S-vacancy concentrations. The free energy diagram of S-vacancy sites (d) and turnover frequencies per surface Mo atom (e) for the samples in (c). Reproduced with permission, ${ }^{89}$ Springer Nature. Defective MoS 2 film fabricated through a helium-ion irradiation method (f) and its corresponding turnover frequency (TOF) at varied vacancy concentrations (g). Reproduced with permission, ${ }^{86}$ American Chemical Society.
low symmetry, and crystalline substrate could also promote the formation of GBs. ${ }^{33,94}$

For example, Zhu et al. firstly calculated the Gibbs free energy of GBs in hetero/homo-phase $\mathrm{MoS}_{2}$ (Fig. 7b). 2H-1T GBs possess extremely low H adsorption energy, which improves the basal plane's activity. ${ }^{93}$ Furthermore, the authors also optimized the $2 \mathrm{H}-1 \mathrm{~T}$ GB density of $\mathrm{MoS}_{2}$ (hundred-nanometers-size domains) by using argon plasma treatments (Fig. 7c). It turned out a very low overpotential of $\sim 136 \mathrm{mV} v$. RHE, a Tafel slope of $\sim 73 \mathrm{mV}$ $\mathrm{dec}^{-1}$, and long-term stability in acidic and alkaline conditions, as shown in Fig. 7d. Alternatively, Lee and co-workers reported the $1 \mathrm{~T}^{\prime}-2 \mathrm{H}$ hetero-phase GBs of $\mathrm{MoTe}_{2}$ via CVD (Fig. 7e). They found a positive linear correlation between the exchange current density and the length of the $\mathrm{MoTe}_{2} 2 \mathrm{H}-1 \mathrm{~T}^{\prime} \mathrm{GBs}$, allowing for an excellent TOF value of $317 \mathrm{~s}^{-1}$ because of the charge accumulation and local band bending at the GBs (Fig. 7f). ${ }^{92}$ To achieve an
ultra-high density of $2 \mathrm{H}-2 \mathrm{H}$ homo-phase GBs, in our previous work, we employed the Au-quantum-dots (QDs)-assisted vaporphase growth in producing sub-10 nm-domain $\mathrm{MoS}_{2}$ films with a GB density up to $\sim 10^{12} \mathrm{~cm}^{-2}$ (Fig. 7 g ). It gave an excellent HER performance (onset potential: $-25 \mathrm{mV} v$. RHE and Tafel slope: $54 \mathrm{mV} \mathrm{dec}{ }^{-1}$ in Fig. 7h). ${ }^{33}$

### 3.4 Phase strategy

Crystal phase-controlled synthesis of TMDCs is a promising strategy that could significantly affect catalytic activity and conductivity as well. Fig. 8a presents various polymorphs of TMDCs, including $2 \mathrm{H}, 3 \mathrm{R}, 1 \mathrm{~T}, 1 \mathrm{~T}^{\prime}$, and $1 \mathrm{~T}_{\mathrm{d}}$ phases, depending on the interaction and coordination between the transition metal and chalcogen. ${ }^{26,100-102}$ Basically, the triangular prismcoordinated TMDCs are typical semiconductors $(2 \mathrm{H}$ or 3 R phase) and have a lower conductivity than metallic octahedral-


Fig. 7 Grain boundary (GB) strategy of 2D-TMDCs for HER. (a) Schematic illustration of the two kinds of GBs: homo-phase and hetero-phase. (b) Comparison of the $\Delta G_{H^{*}}$ on $2 \mathrm{H}-\mathrm{MoS}_{2}, 1 \mathrm{~T}-\mathrm{MoS}_{2}, \mathrm{Pt}(111)$, and $2 \mathrm{H}-1 \mathrm{~T}$ hetero-phase GB , and $2 \mathrm{H}-2 \mathrm{H}$ homo-phase GB. Reproduced with permission, ${ }^{93}$ Springer Nature. STM image of the $2 \mathrm{H}-1 T$ hetero-phase GB of $\mathrm{MoS}_{2}$ (c) and the polarization curves with varied GB densities (d). Reproduced with permission, ${ }^{93}$ Springer Nature. Charge potential mapping across a $1 \mathrm{~T}^{\prime}-2 \mathrm{H}$ hetero-phase GB of MoTe $\mathrm{e}_{2}$ (e) and its exchange-current-density as a function of the GB length ( $f$ ). Reproduced with permission, ${ }^{92}$ Wiley-VCH. Atomic structures of $2 \mathrm{H}-2 \mathrm{H}$ homo-phase GBs in the $\mathrm{MoS}_{2}$ nanograin film ( g ) and their polarization curves $(\mathrm{h})$ obtained from the microcells. Reproduced with permission, ${ }^{33}$ Springer Nature.
coordinated ones. ${ }^{103,104}$ In the past, various strategies have been used to synthesize metal-phase group VI TMDCs, such as alkali metal intercalation, ${ }^{28,101,104-108}$ electron beam irradiation, ${ }^{104,109}$ plasma bombardment, ${ }^{110}$ pressure and strain, ${ }^{111}$ high magnetic field hydrothermal reaction, ${ }^{112}$ and electrostatic doping,, ${ }^{113}$ Using the first-principles calculations, Fan and co-workers suggested that only the basal plane of $1 \mathrm{~T}^{\prime}-\mathrm{MoS}_{2}$ should be active in the HER, contrary to $2 \mathrm{H}-\mathrm{MoS}_{2}$ (Fig. 8b). ${ }^{114}$ Unfortunately, it was found in the experiments that most 1 T or $1 \mathrm{~T}^{\prime}$ phase TMDCs are metastable and easily converted into their 2 H counterparts. ${ }^{26,106}$ To abbreviate this issue, Voiry et al. adopted
the Li-intercalation-based chemical-exfoliation method to produce stable $1 \mathrm{~T}-\mathrm{MoS}_{2}$ nanosheets with a negatively-charged surface. Those nanosheets exhibited an excellent catalytic activity toward HER (Fig. 8c). ${ }^{28}$ Subsequently, Liu and Yu et al. designed an alkali metal atom (K)-assisted CVD method for growing stable $1 \mathrm{~T}^{\prime}$-TMDC monolayers (such as $\mathrm{MoS}_{2}, \mathrm{WS}_{2}$, $\mathrm{WSe}_{2}, \mathrm{MoSe}_{2}$ ), as shown in Fig. 8d. ${ }^{104,105}$ They claimed that the intercalation of alkali metals could significantly reduce the formation energy of the metal phase TMDCs. A better HER performance was also observed in their samples compared to that of 2 H phases, as shown in Fig. 8e. To more clearly elaborate
a

b


| $\Delta \mathrm{G}_{\mathrm{H}}(\mathrm{eV})$ | Site 1 | Site 1,2 | Site 1,3 | Site 1,5 | Site 1,6 | Site 1,8 |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $1 \mathrm{H}-\mathrm{MoS}_{2}$ | 1.8 | 1.29 | 1.50 | 1.37 | 1.54 | 1.51 |
| $1 \mathrm{~T}-\mathrm{MoS}_{2}$ | 2.67 | 0.63 | 0.63 | 0.28 | 0.60 | 0.69 |
| $1 \mathrm{~T}^{\prime}-\mathrm{MoS}_{2}$ | $0.06\left(0.73^{*}\right)$ | 0.22 | 0.20 | 0.11 | 0.07 | $0.85^{*}$ |

d

e


C

g

f


Fig. 8 Phase-engineering strategy of 2D-TMDCs for HER. (a) Schematic illustration of the different phase structures of TMDCs. Reproduced with permission, ${ }^{26}$ Springer Nature. (b) The first and second $H$ structures adsorbed on the surfaces of $1 \mathrm{H}, 1 \mathrm{~T}$, and $1 T^{\prime}$ MoS ${ }_{2}$, and the correspondingly calculated Gibbs free energy, respectively. Reproduced with permission, ${ }^{114}$ Royal Society of Chemistry. (c) HER activity of solution-exfoliated 1T and $2 \mathrm{H} \mathrm{MoS}_{2}$ nanosheets. Reproduced with permission, ${ }^{28}$ American Chemical Society. Phase-controlled CVD strategy of $1 T^{\prime}$ MoS ${ }_{2}$ monolayer (d) and its corresponding polarization curve (e). Reproduced with permission, ${ }^{105}$ Springer Nature. The fabrication process of three types (EM-1, EM-2, and EM-3) of electrochemical microcells ( $f$ ) and their corresponding HER performances. Inset: optical microscopy image of EM-1. Scale bar, 20 $\mu \mathrm{m}(\mathrm{g})$. Reproduced with permission, ${ }^{29}$ Springer Nature.
on the activity of the $1 \mathrm{~T}^{\prime}$ phase, Yu et al. employed both thermal annealing and laser irradiation to realize a smooth phase transformation from $1 \mathrm{~T}^{\prime}-\mathrm{MoS}_{2}$ to $2 \mathrm{H}-\mathrm{MoS}_{2}$, and verify the enhanced HER activity solely based on the $1 \mathrm{~T}^{\prime}$ basal phase using three microcells (Fig. 8f and g). ${ }^{104}$

### 3.5 Superlattice strategy

With the help of topological physics engineering, superlattices can optimize the electronic structure and energy bands of TMDC catalysts. ${ }^{115-117}$ There are two types of superlattices: traditional (periodic stacking of different layered materials) and
moiré ones (twisted structure of similar 2D bilayers), as shown in Fig. 9a. Most TMDC superlattices with different stacking orders and twists between layers have been obtained by layer-bylayer restacking, ${ }^{118-120}$ CVD, ${ }^{121}$ laser molecular beam epitaxy (LMBE), ${ }^{122,123}$ electrochemical-molecular intercalation, ${ }^{59,124}$ hydrothermal methods, ${ }^{125,126}$ capillary-force-driven rolling-up, ${ }^{127}$ etc.

In theory, Xiong et al. demonstrated the bilayer models of $\mathrm{MoS}_{2} /$ graphene, layered double hydroxide (LDH)/G, and $\mathrm{MoS}_{2} /$ LDH superlattices for HER. The enhanced electrocatalytic
activity was observed in $\mathrm{MoS}_{2} / \mathrm{LDH}$, attributed to significant electron accumulation at its interface that could modulate the intermediates' adsorption energies in HER pathways (Fig. 9b). ${ }^{128}$ In the experiment, Guo et al. developed an $n$-type $\mathrm{TaS}_{2}-\mathrm{N}_{2} \mathrm{H}_{4}$ hybrid superlattice through a spontaneous molecular-intercalation method at room temperature (Fig. 9c). It has high electrical conductivity and a low work function, confirmed by the Kelvin probe force microscope (KPFM), showing an excellent HER activity (Fig. 9d). ${ }^{59}$ On the other hand, using an LMBE technique, Jiang et al. reported a bilayer $\mathrm{MoS}_{2}$
a Superlattice strategy for HER


Traditional superlattice


Moire superlattice
b


C

e

g

d


h


Fig. 9 Superlattice strategy of 2D-TMDCs for HER. (a) Schematic illustration of two kinds of superlattices: traditional superlattice (left) and moiré
 (LDH). Reproduced with permission, ${ }^{128}$ American Chemical Society. The atomic structure of the $\mathrm{TaS}_{2}-\mathrm{N}_{2} \mathrm{H}_{4}$ hybrid superlattice (c) and its corresponding HER performance (d). Reproduced with permission, ${ }^{59}$ American Chemical Society. Structures of the moiré superlattice of a MoS 2 nanoscroll (e) and the corresponding polarization curves (iR-corrected) (f). Reproduced with permission, ${ }^{123}$ American Chemical Society. Highresolution transmission electron microscopy (HRTEM) image of the $W_{2}$ moiré superlattice formed by a layer-slipping method ( g ) and the corresponding iR-corrected polarization curves (h). Scale bar, 1 nm . Yellow and cyan balls represent S and W atoms, respectively. Reproduced with permission, ${ }^{126}$ Springer Nature.
nanoscroll (twisted angle $\theta \approx 7.3^{\circ}$ ) having a moiré superlattice structure (Fig. 9e). Such a structure could extremely reduce the interlayer potential barrier to improve the hopping efficiency of electron transfer, achieving a boosted electrocatalytic performance with $\eta_{10}$ of $-153 \mathrm{mV} v s$. RHE and Tafel slope of 73 mV dec ${ }^{-1}$, as shown in Fig. 9f. ${ }^{123}$ Additionally, Xie and co-workers found a nanoconical array $\mathrm{WS}_{2}$ with moiré superlattices (Fig. 9g), showing an intriguing HER performance (the low overpotential $\eta_{10}$ of $60 \mathrm{mV} v s$. RHE in the Fig. 9h). ${ }^{126}$ The underlying mechanism is attributed to the fact that the twisted $\mathrm{WS}_{2}$ bilayer has lower Gibbs free energy than the normal $\mathrm{WS}_{2}$. The above approaches have enriched our current toolbox for designing superlattices and provide great potential for watersplitting applications.

## 4. External regulation

Besides the above internal methods, external control methods, such as the electric field, strain, substrates, and heterostructures, have attracted considerable interest in activating the basal plane with a high degree of freedom. ${ }^{36}$ For example, the applied electric field and strain can realize a smooth tunning of their catalytic activities. Conductive-carbon-based or metalbased substrates provide alternatives to improving the electron-injection efficiency for HER. Constructing HER-active materials (such as hydroxides, oxides, and carbides) onto TMDC basal planes to form the heterostructures presents another promising strategy.

### 4.1 Electric-field strategy

Applying a vertical electric field on TMDCs could enhance the HER efficiency by increasing the electrical conductivity, reducing the $\Delta G_{\mathrm{H}^{*}}$, as well as adjusting the distribution of reactants. ${ }^{104,129,130}$ It can serve as a high-degree-of-freedom strategy for tuning the basal plane activity of TMDCs smoothly. ${ }^{36}$ In 2017, Mai et al. first explored the influence of the electric field on the $\mathrm{MoS}_{2}$ nanosheet through a back-gate microcell (Fig. 10b). ${ }^{131}$ They observed that in the absence of an electric field, a current density of $100 \mathrm{~mA} \mathrm{~cm}{ }^{-2}$ required an overpotential of 240 mV . However, as the gate voltages increased up to 5 V , a significantly-reduced overpotential (down to 38 mV ) was achieved, comparable to that of the Pt electrode, as shown in Fig. 10c. This improved HER efficiency could be attributed to lowering both $\mathrm{MoS}_{2}$ itself resistance and the $\mathrm{Au}-$ $\mathrm{MoS}_{2}$ contact barrier under a positive electric field. Later, a similar phenomenon was also observed in other works, ${ }^{132-134}$ further confirming that the electric field can improve the electron injection process during the HER process.

Except for the improvement of the conductivity, the electric field can also regulate the $\Delta G_{\mathrm{H}^{*}}$ of the TMDCs basal planes or adjust the distribution of reactants in an electrolyte. For example, Frisbie et al. developed an electrochemical flow cell allowing the simultaneous measurements of electrical and electrochemical properties (Fig. 10d). However, they rarely observed a change in the sheet resistance of the monolayer $\mathrm{MoS}_{2}$ when increasing the back-gate voltages (Fig. 10e), ${ }^{135}$

Alternatively, a significant drop in $\Delta G_{\mathrm{H}^{*}}$ was found because the Mo atoms next to the $S$ vacancies on the basal plane accumulate excess electrons under the positive electric field, resulting in an enhanced HER performance. ${ }^{136}$ Those results suggested that the electric field dominates $\Delta G_{\mathrm{H}^{*}}$ of the monolayer $\mathrm{MoS}_{2}$ rather than its conductivity in HER. A similar phenomenon was also observed in bipolar semiconductors. ${ }^{45}$ Fig. 10f shows H atoms adsorbed on a $\mathrm{WSe}_{2}$ nanosheet, as obtained from the DFT calculations. The positive electric field provided more electron carriers for the bipolar $\mathrm{WS}_{2}$, reducing the free energy (Fig. 10g).

The electric field can also adjust the distribution of charged reactants at the catalyst-electrolyte interface during the HER process. ${ }^{137}$ Mai et al. used metallic $\mathrm{VSe}_{2}$ as the working electrode and found that $\mathrm{H}_{3} \mathrm{O}^{+}$prefers to accumulate at the interface (Fig. 10h and i). ${ }^{110}$ Therefore, they claimed that the Volmer step in the HER process was accelerated, thus increasing the overall reaction rate. It is worth emphasizing that the electric field regulation is a complex strategy. One or more factors, such as the contact barrier of the whole system, the concentration of reactants, the conductivity of catalysts, and the transfer process of charges, would affect the reaction.

### 4.2 Strain strategy

Due to their atomic thickness, TMDC nanosheets are very sensitive to strain, ${ }^{138-140}$ while impressively, they can withstand up to 23 GPa ( $11 \%$ ) mechanical strain. ${ }^{141}$ According to the dband model, ${ }^{142-144}$ the strength of H adsorption on the catalyst is crucial to the d-band position, and a tensile strain can upshift it to reduce occupied states of antibonding orbitals, promoting the H -atom adsorption. ${ }^{145,146}$ This electronic theory could also be suitable for strained TMDCs, ${ }^{146}$ and the strain would play a vital role in the H adsorption during the HER process. Here, we discuss three strain strategies: lattice mismatch, bending substrates, and textured strain.

A lattice mismatch can induce a local strain on TMDC materials. ${ }^{147-149}$ For example, Chhowalla et al. prepared highly distorted $1 \mathrm{~T}-\mathrm{WS}_{2}$ nanosheets using an intercalation-based chemical exfoliation method. ${ }^{42}$ The STEM image shows a lattice mismatch in $\mathrm{WS}_{2}$ nanosheets (Fig. 11c), and the inset confirmed that this mismatch could cause a large area of local strain (about 3\%) on the basal plane. As a result, the free energy could be tuned to be close to 0 when the strain value was $2.7 \%$, showing an excellent performance of the highly distorted 1T$\mathrm{WS}_{2}$ nanosheets (Fig. 11d).

Being different from the above lattice mismatch, constructing bending strain and texture strain usually requires templates such as 3D nanoporous gold (NPG), ${ }^{150,151}$ nanofibers, ${ }^{152}$ polymer substrate, ${ }^{153}$ and nanocones. ${ }^{32,154}$ For example, Tan et al. constructed single-Ru-atom-anchored nanoporous $\mathrm{MoS}_{2}$ (denoted as $\mathrm{Ru} / \mathrm{np}-\mathrm{MoS}_{2}$ ) by NPG (Fig. 11e). ${ }^{151}$ It was found that the curved structure could introduce strain around the Ru-atom in the basal plane, the strength of which was tailored simply by the sample's ligament size. A larger strain in the Ru/np-MoS2 catalyst results in better performance, and a $\eta_{10}$ of 30 mV , as well as a Tafel slope of $31 \mathrm{mV} \mathrm{dec}{ }^{-1}$, was finally achieved, as shown in Fig. 11f. Operando X-ray absorption spectroscopy (XAS) revealed that the


Fig. 10 Electric field strategy of 2D-TMDCs for HER. (a) Schematic illustration of the electric field strategy for HER. (b) Schematic illustration of a three-electrode microcell based on a $\mathrm{MoS}_{2}$ nanosheet for HER measurement. (c) Polarization curves at varied back-gate voltages, as obtained from the micro-cell in (b). Reproduced with permission, ${ }^{131} \mathrm{Wiley-VCH}$. (d) The structure of a back-gated microcell. Inset: the optical images of a $\mathrm{MoS}_{2}$-monolayer electrode. (e) The normalized sheet resistance of the $\mathrm{MoS}_{2}$ electrode as a function of the electrode potential ( $V_{w}$ ) at varied back-gate voltages ( $V_{\mathrm{BG}}$ ). Reproduced with permission, ${ }^{135}$ American Chemical Society. ( $f$ ) DFT calculation of an H -atom adsorbed on a WSe 2 nanosheet charged by the back-gate voltage (blue, purple, and green balls represent Se, W, and H atoms, respectively). (g) The Gibbs free-energy diagram of $\mathrm{WSe}_{2}$ under different carrier concentrations. Reproduced with permission, ${ }^{45}$ Wiley-VCH. (h) COMSOL simulation of the net charge distribution on the surface of a $\mathrm{VSe}_{2}$ electrode at varied back-gate voltages. (i) Simulation results of charge concentrations on the surface (lines and dots represent $\mathrm{H}^{+}$and $\mathrm{SO}_{4}{ }^{2-}$, respectively). Inset: the net charge as a function of back-gate voltage. Reproduced with permission, ${ }^{110}$ American Chemical Society.
strain could accelerate the mass transfer from the S-vacancy sites to Ru sites, amplifying the synergetic interaction between them. In another example, Li et al. created a wide range of texture strains on the basal plane of $\mathrm{MoS}_{2}$ using a nanocone array method (Fig. 11g). ${ }^{32}$ After comparing $\mathrm{MoS}_{2}$, strain-only $\mathrm{MoS}_{2}$ (S$\mathrm{MoS}_{2}$ ), and vacancy-only $\mathrm{MoS}_{2}\left(\mathrm{~V}-\mathrm{MoS}_{2}\right)$, strained-vacancy $\mathrm{MoS}_{2}$ $\left(S V-\mathrm{MoS}_{2}\right)$ gave the best HER performance with a $\eta_{10}$ of 170 mV , as shown in Fig. 11h (green areas referred to the contribution of strain to reactivity). They claimed that the tensile strain could narrow the $\mathrm{MoS}_{2}$ bandwidth and shift the free energy toward thermoneutrality, thus enhancing the HER activity. It is worth mentioning that the strain, in combination with other methods,
e.g., vacancies, ${ }^{87}$ can provide a more flexible way to regulate the catalytic performance of the basal planes.

### 4.3 Substrate strategy

The underlying substrates have been confirmed to facilitate the electron injection and modify the chemical property of catalysts to improve catalytic performance, that is, the substrate effect. ${ }^{27,157,158}$ The conductive substrates can be classified into carbon materials and pure metals. The former mainly includes carbon black, ${ }^{159}$ graphenes, ${ }^{155,160,161}$ carbon nanotubes, ${ }^{162,163}$ and carbon fiber. ${ }^{156}$ The latter are $\mathrm{Au}, \mathrm{Ti}, \mathrm{Ni}$,


Fig. 11 Strain strategy of 2D-TMDCs for HER. (a) Schematic illustration of the strain strategy for HER. (b) The energy diagrams of the influence of tensile strain on the d-band position in late transition metals. Reproduced with permission, ${ }^{145}$ Springer Nature. (c) High-resolution scanning transmission electron microscopy (STEM) images of the as-exfoliated $\mathrm{WS}_{2}$. Inset: the strain tensor mapping obtained from the STEM images (black and yellow colors correspond to compressed and tensile regions). Scale bar, 1 nm . (d) The Gibbs free energy of $1 T-W S_{2}$ varied by the tensile strain. Reproduced with permission, ${ }^{42}$ Springer Nature. (e) Schematic illustration of the Ru/nanoporous MoS $\mathrm{S}_{2}(\mathrm{Ru} / \mathrm{np}-\mathrm{MoS} 2$ ). SV indicates sulfur vacancies. (f) Polarization curves of $\mathrm{Ru} / \mathrm{np}-\mathrm{MoS}_{2}$, in comparison to those of nanoporous $\mathrm{MoS}_{2}(\mathrm{np}-\mathrm{MoS}$ ), Ru/plane $\mathrm{MoS} 2(\mathrm{Ru} / \mathrm{P}-\mathrm{MoS} 2$ ), and Ru/larger ligament nanoporous $\mathrm{MoS}_{2}\left(\mathrm{Ru} / \mathrm{Lnp}-\mathrm{MoS}_{2}\right)$. Reproduced with permission, ${ }^{151}$ Springer Nature. (g) False-color SEM image of a 2D strained $\mathrm{MoS}_{2}$ monolayer on a nanocone array. Scale bar, $1 \mu \mathrm{~m}$. Reproduced with permission, ${ }^{154}$ Springer Nature. (h) Polarization curves of strained-vacancy $\mathrm{MoS}_{2}\left(\mathrm{SV}-\mathrm{MoS}_{2}\right)$, in comparison to those of the Au substrate, pristine $\mathrm{MoS}_{2}$, strained MoS ( $\mathrm{S}-\mathrm{MoS} 2$ ), and MoS 2 with vacancies $\left(\mathrm{V}-\mathrm{MoS}_{2}\right)$. Reproduced with permission, ${ }^{32}$ Springer Nature.

Pt, and so on. ${ }^{40}$ The typical substrate is graphene. Shin et al. fabricated $\mathrm{WS}_{2} /$ reduced graphene oxide $\left(\mathrm{WS}_{2} / \mathrm{rGO}\right)$ hybrid nanosheets using conductive rGO as the substrate (Fig. 12b). ${ }^{155}$ Since the rGO substrate facilitates a rapid electron transfer to the $\mathrm{WS}_{2}$ catalyst, $\mathrm{WS}_{2} / \mathrm{rGO}$ nanosheets enhance HER performance compared with $\mathrm{WS}_{2}$ alone, as shown in Fig. 12c. Extending to metal substrates, Liu et al. systematically investigated the catalytic performance of $\mathrm{TaS}_{2}$ on the glass carbon plate, carbon fiber, Mo foil, and Au foil. ${ }^{156}$ Among those substrates, the authors found that $\mathrm{Au} / \mathrm{TaS}_{2}$ has the best catalytic performance ( $33 \mathrm{mV} \mathrm{dec}{ }^{-1}$ of Tafel plot in Fig. 12d) with the lowest $\Delta G_{\mathrm{H}^{*}}$ (Fig. 12e), which results from the ideal lattice mismatch at the $\mathrm{TaS}_{2}-\mathrm{Au}$ interface (Fig. 12f).

On the other hand, substrates could also induce carrier doping to modify the activity of TMDC catalysts. ${ }^{164,165}$ For instance, Cao et al. observed substrate-induced $n$-doping of the monolayer $\mathrm{MoS}_{2}$ through the redshift of Raman spectra (Fig. 12g). ${ }^{40}$ The DFT shows that such doping would improve the activity of the vacancies to activate the $\mathrm{MoS}_{2}$ basal plane (Fig. 12h), and a higher doping level ( $\mathrm{Pt}>\mathrm{Ni}>\mathrm{Ti}>\mathrm{Au}$ ) leads to lower adsorption energy of the sample, agreeing with the experiment results (Fig. 12i).

### 4.4 Heterostructure strategy

Heterostructures that were rationally designed by combining the advantages of each TMDC component together would


Fig. 12 Substrate strategy of 2D-TMDCs for HER. (a) Schematic illustration of the substrate strategy for HER. (b) HRTEM image of the WS ${ }_{2} /$ reduced graphene oxide $\left(\mathrm{WS}_{2} / \mathrm{rGO}\right)$ hybrid nanosheet. Inset: the zoom-in image of the $\mathrm{WS}_{2}$ nanosheet. (c) Polarization curves of the annealed $\mathrm{WS}_{2} / r G O$ hybrid nanosheets, in comparison to those of annealed $\mathrm{WS}_{2}$ nanosheets and $\mathrm{WS}_{2} / \mathrm{rGO}$ hybrid nanosheets. Reproduced with permission, ${ }^{155}$ Wiley-VCH. (d) Tafel plots of $\mathrm{TaS}_{2}$ samples on glass carbon (GC), carbon fibers (CF), Mo, and Au substrates. (e) The $\Delta G_{H^{*}}$ of the TaS 2 nanosheet under the lattice-mismatch condition. (f) Schematic illustration of the substrate effect on a TaS 2 electrocatalyst. Reproduced with permission, ${ }^{156}$ American Chemical Society. (g) Raman spectra of monolayer MoS ${ }_{2}$ on $\mathrm{Au}, \mathrm{GC}, \mathrm{Ti}, \mathrm{Ni}$, and Pt substrates, showing the redshift of Pt > $\mathrm{Ni}>\mathrm{Ti}>\mathrm{Au}$. (h) Schematic illustration of the substrate effect on a $\mathrm{MoS}_{2}$ monolayer. (i) Calculated hydrogen adsorption energies and the measured Tafel slopes of $\mathrm{MoS}_{2}$ monolayer on Pt, Ni, Ti, and Au substrates. Reproduced with permission, ${ }^{40}$ American Chemical Society.
possess a higher catalytic performance than those single components. ${ }^{14,166,167}$ Here, we would discuss the synergistic effect ${ }^{168,169}$ and the interfacial charge transfer ${ }^{170-172}$ originating from heterostructures. So far, the synergistic effects have also been frequently observed in hydroxide/TMDC, ${ }^{173-176}$ TMDC/ TMDC, ${ }^{177-180}$ oxide/TMDC, ${ }^{181-183}$ and others. ${ }^{184-187}$ As discussed in Section 2, the high adsorption energy of $\mathrm{H}_{2} \mathrm{O}$ hinders the generation of $\mathrm{H}_{\mathrm{ad}}$ intermediates, leading to sluggish kinetics in alkaline solution. To optimize HER pathways, Jiang et al. prepared a $\mathrm{Ni}(\mathrm{OH})_{2} / \mathrm{MoS}_{2}$ heterostructure, in which $\mathrm{Ni}(\mathrm{OH})_{2}$ could serve as the dissociation promoter, thereafter, $\mathrm{H}_{2}$ was generated on the $\mathrm{MoS}_{2}$ basal plane. ${ }^{188}$ DFT calculations also confirmed this synergistic effect, which could lower the $\mathrm{H}_{2} \mathrm{O}$ adsorption energy from 0.75 eV to 0.05 eV , significantly
accelerating the reaction kinetics. A Tafel plot of $60 \mathrm{mV} \mathrm{dec}{ }^{-1}$ was finally obtained in this heterostructure, much better than that of the pristine basal plane ( $96 \mathrm{mV} \mathrm{dec}{ }^{-1}$ ), as shown in Fig. 13d.

It was found that heterostructures could also optimize the electronic structure and the mass/electron transfer. For example, Cha et al. synthesized $\mathrm{MoS}_{2} / \mathrm{WTe}_{2}$ vertical heterostructure with semi-metallic $\mathrm{WTe}_{2}$ as the bottom layer. ${ }^{189}$ They claimed that a low Schottky barrier in the heterostructure tends to rapidly inject electrons from the bottom $\mathrm{WTe}_{2}$ to the top $\mathrm{MoS}_{2}$. Consequently, the catalytic activity of $\mathrm{MoS}_{2}$ in the heterostructure is better than that of the $\mathrm{WTe}_{2}$ edge-contacted one. That is, the former had a larger contact area than the latter (Fig. 13g), thus showing a shorter pathway of charge


Fig. 13 Heterostructure strategy of 2D-TMDCs for HER. (a) Schematic illustration of the heterostructure strategy for HER. (b) Schematic illustration of the water activation process for the $\mathrm{Ni}(\mathrm{OH})_{2} / \mathrm{MoS}_{2}$ heterostructure in an alkaline solution. $\mathrm{H}, \mathrm{O}, \mathrm{Mo}, \mathrm{S}$, and Ni atoms are shown in white, red, cyan, yellow, and blue, respectively. The free energy diagram (c) and the Tafel plots (d) for $\mathrm{MoS} \mathrm{S}_{2}, \mathrm{Ni}(\mathrm{OH})_{2}, a n d \mathrm{Ni}(\mathrm{OH})_{2} / \mathrm{MoS} 2$. Reproduced with permission, ${ }^{188}$ Elsevier. (e) The aligned band structure of the $\mathrm{MoS}_{2} / \mathrm{WTe} e_{2}$ heterostructure. (f) The corresponding polarization curves of the $\mathrm{MoS}_{2} / \mathrm{WTe}_{2}$ heterostructure. ( g ) Comparison of the HER mechanisms of the $\mathrm{MoS}_{2} / \mathrm{WTe}_{2}$ heterostructure (bottom) and MoS ${ }_{2}$ with $\mathrm{WTe}_{2}$ edge-contact (top). Reproduced with permission, ${ }^{189}$ Wiley-VCH. HRTEM image (h) and the TOF(I) of the in-plane $1 \mathrm{~T}-2 \mathrm{H}$ MoS 2 heterostructure. Reproduced with permission, ${ }^{125}$ Wiley-VCH.
during the HER process. In another example, Yang et al. reported a stable in-plane $1 \mathrm{~T}-2 \mathrm{H} \mathrm{MoS}_{2}$ heterostructure using an annealing treatment method (Fig. 13h). ${ }^{125}$ They demonstrated a huge improvement in HER properties in the alkaline solution (TOF: 13.14 and $1.61 \mathrm{H}_{2} \mathrm{~s}^{-1}$ at 250 mV for heterostructure and $2 \mathrm{H}-\mathrm{MoS}_{2}$ nanosheet, respectively), as shown in Fig. 13i. This enhancement was attributed to the rapid electron transport and abundant active sites, both of which facilitate activating the inert basal plane of $2 \mathrm{H}-\mathrm{MoS}_{2}$. It can be seen that those above heterostructures can combine the advantages of each component, significantly activating the basal plane of TMDCs. What is more, the recent emergence of machine learning could assist in screening the types and structures, ${ }^{190}$ which will be helpful in the design of high-performance heterostructure catalysts.

## 5. Summary and outlook

Electrocatalytic hydrogen production, basically, is an interfacial reaction, where the adsorption and desorption behavior of hydrogen atoms, that is, $\Delta G_{\mathrm{H}^{*}}$ as an important parameter, dominate the reaction rate. Benefiting from their stable and atom-thin ( $<1 \mathrm{~nm}$ ) nature, 2D TMDCs themselves act as an interface and possess the potential of exposing nearly all of their atoms to the electrolyte. This unique character makes 2D TMDC ideal candidates for HER catalysts and the corresponding mechanism study. Unfortunately, in respect of most nonmetallic TMDCs, their basal plane is usually inert. In the past ten years, substantial studies have thus been undertaken to activate the basal plane through strategies based on internal regulation such as doping, vacancies, phases, GBs, superlattices, or external regulation, such as the electric field, strain, substrates, and heterostructures. We summarized the
characteristics of all strategies mentioned above in Table 1 and enumerated their corresponding principles, active types, and representative examples. Among them, some strategies activate the basal plane by creating dispersed active sites, such as doping, vacancies, and GBs. In contrast, the others did it by modulating the whole plane's activity lane, such as phases, superlattices, the electric field, and heterostructures.

Although significant progress has been made to improve the HER activity of TMDC's basal planes, some challenges remain in the above strategies. For example, with respect to the dispersed active sites, the activating effectiveness depends largely on their intrinsic activity and density, however, a high density of the sites (for example, vacancies) will destroy the 2D layered structure. Therefore, we need to strike a balance between the activity and stability for those activating strategies since both will affect the key figure of merit of HER performances. On the other hand, adopting phase-transition, superlattices, and heterostructures enable a whole active layer of 2D TMDCs, while their structural stability and reproducibility are still challenges. For example, octahedrally-coordinated 1Tphase and intercalated hybrid superlattices have low
thermodynamic stability. Alternatively, the electric field and heterostructures also lead to a whole active layer, however, their mechanisms are still challenging to clarify, such as the interlayer coupling in heterostructures, and the apparent differences among the electron injection, and electron transport, as well as ion-redistribution under the applied electric field.

Despite the above challenges, there are also many intriguing directions for efficiently activating TMDC's basal planes. Here, we provide personal perspectives on opportunities to be explored in this emerging field.

The first is a joint strategy. Such strategies have their own advantages or disadvantages, as discussed above. They would rouse a joint strategy that can combine two or three strategies to make full use of all their advantages (that is, one plus one is greater than two). A typical example is strained-S vacancies in the $\mathrm{MoS}_{2}$ basal plane. ${ }^{32}$ For only SVs, increasing their concentrations would continually lower $\Delta G_{\mathrm{H}^{*}}$, while its high level ( $>19 \%$ ) would lead to poor stability. On the other hand, it is insufficient to activate the basal plane only by the strain strategy, even at a high strain. Interestingly, taking them together would only require $\sim 11 \%$ of SVs to realize an optimal

Table 1 Summary of the strategies for activating the TMDC basal planes

| Strategy | Principle | Active types | Examples | Material/ structure | $\begin{aligned} & \eta_{10} \\ & (\mathrm{mV}) \end{aligned}$ | Tafel slope (mV $\mathrm{dec}^{-1}$ ) | Electrolyte | Ref. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Doping | Engineer locally uncoordinated active sites | Dispersed sites | Metal-doping | $\mathrm{Pd}-\mathrm{MoS}_{2}$ | 89 | 62 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 62 |
|  |  |  | Nonmetal-doping | Carbon-MoS ${ }_{2}$ | 45 | 46 | 1 M KOH | 79 |
| Vacancies | Engineer locally unsaturated site | Dispersed sites | Isolated-S vacancies | $30 \mathrm{He}^{+}-\mathrm{MoS}_{2}$ | 200 | 90 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 86 |
|  |  |  | Cluster-S vacancies | Repaired 2H- | 300 | 85 | 0.5 M | 88 |
|  |  |  | $1 \mathrm{~T}^{\prime}$ phase17 phase |  |  | 100 | $\begin{aligned} & \mathrm{H}_{2} \mathrm{SO}_{4} \\ & 0.5 \mathrm{M} \end{aligned}$ |  |
| Phases | Increase the conductivity and lower the hydrogen absorption energy | Whole plane |  | $1 \mathrm{~T}^{\prime}-\mathrm{MoS}_{2}$$1 \mathrm{~T}-\mathrm{MoS}_{2}$ | 65 |  | $\begin{aligned} & \mathrm{H}_{2} \mathrm{SO}_{4} \\ & 0.5 \mathrm{M} \end{aligned}$ | 29 |
|  |  |  |  |  |  |  | $\mathrm{H}_{2} \mathrm{SO}_{4}$ |  |
| GBs | Engineer unsaturated-site 1D channel | Dispersed 1D sites | 2H-2H GBs | $\mathrm{MoS}_{2}$ nanograin film | 25 | 50 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 33 |
|  |  |  | 2H-1T GBs | $2 \mathrm{H}-1 \mathrm{~T}-\mathrm{MoS}_{2} \mathrm{~GB}$ | 260 | 85 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 93 |
| Superlattices | Improve the activity by interfacial electronic coupling | Whole plane | Moiré superlattice | $\mathrm{WS}_{2}$ moiré superlattice | 60 | 42 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 126 |
|  |  |  | Layer-stacked superlattice | $\mathrm{TaS}_{2} / \mathrm{N}_{2} \mathrm{H}_{4}$ superlattice | 0.4 | 76 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 191 |
| Electric field | Facilitate electron injection and ion-redistribution | Whole plane | Vertical electric field | Monolayer $\mathrm{MoS}_{2}$ | 176 | 100 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 135 |
| Strain | Lower the hydrogen absorption energy | Dispersed sites | Lattice-mismatch induced stain | Distorted 1T WS ${ }_{2}$ | 235 | 60 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 42 |
|  |  |  | Bending stain | $\mathrm{Ru} /$ nanoporous $\mathrm{MoS}_{2}$ | 30 | 31 | 1 M KOH | 151 |
|  |  |  | Textured strain | Strained-vacancy $\mathrm{MoS}_{2}$ | 131 | 48 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 32 |
| Substrates | Enhance electron injection, and activity by doping | Whole plane | Metal-based substrates | $\mathrm{TaS}_{2}$ on Au | 101 | 53 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 156 |
|  |  |  | Carbon-based substrates | $\mathrm{WS}_{2}$ on rGO | 264 | 58 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 155 |
| Heterostructu | Synergistic effect | Whole plane | Hydroxide/TMD heterostructure | $\mathrm{Ni}(\mathrm{OH})_{2} / \mathrm{MoS}_{2}$ | 80 | 60 | 1 M KOH | 188 |
|  | Accelerate interfacial charge transfer | Whole plane | TMD/TMD heterostructure | $\mathrm{MoS}_{2} / \mathrm{WTe}_{2}$ | 135 | 40 | $\begin{aligned} & 0.5 \mathrm{M} \\ & \mathrm{H}_{2} \mathrm{SO}_{4} \end{aligned}$ | 189 |

condition of $\Delta G_{\mathrm{H}^{*}}=0 \mathrm{eV}$, which helps preserve the stability of the layered structures.

Second, phase-engineering TMDC strategy. As an important parameter of layered TMDs, the crystal phase is usually decisive to their properties. For example, most 2 H TMDCs, e.g., $2 \mathrm{H}-$ $\mathrm{MoS}_{2}, \mathrm{MoSe}_{2}, \mathrm{WS}_{2}, \mathrm{WSe}_{2}$, etc., are very stable in air/water and can withstand the acidic/basic electrolyte as well as high temperatures ( $>400^{\circ} \mathrm{C}$ in hydrogen atmosphere), while the only drawback they meet is the inertness of the basal plane for HER. On the contrary, their metallic counterparts, such as 1T- $\mathrm{MoS}_{2}$, and $1 \mathrm{~T}^{\prime}-\mathrm{MoS}_{2}$, the whole basal planes are HER-active. However, their large-scale or pure-phase syntheses remain challenging to date due to their metastable nature. Therefore, under a trade-off of structural stability and HER activity, phase-engineering TMDC materials, such as $2 \mathrm{H}-1 \mathrm{~T}$ phase transform or direct 1 T phase-controlled synthesis, would present a promising strategy to activate the basal plane in a sampling manner.

The third is electrical-electrocatalytic coupling. From a charge-flowing point of view, a typical electrocatalytic process usually involves three steps, including the first charge injection step from the conductive substrate to the catalyst, the later charge transport step inner the catalyst body, and finally, the charge transfer at the sites at the solid-liquid interface. It can be seen that, besides the activity sites, both the charge injection and transport steps are the key factors affecting the reaction happens. For example, Voiry et al. improved the electron injection (the first step) from the Au electrode to the $2 \mathrm{H}-\mathrm{MoS}_{2}$ catalyst using phase-engineered low-resistance contacts and achieved comparable performance to metallic edges and the 1T phase. ${ }^{30}$ In another example, He et al. observed a self-gating effect at the TMDC nanosheet-electrolyte interface, ${ }^{192}$ demonstrating that the electrocatalytic reaction itself can strongly modulate the conductance (the second step) of TMDC. Moreover, their semiconducting types (n, p, or bipolar) could strongly correlate with their electrocatalytic reactions (HER, OER, or both). Those typical works indicate the potential importance of electrical-electrocatalytic coupling in the HER process, which needs to be considered when exploring new activating strategies.

Last, but not least, is the potential of "single-atom-layer" catalysis. In our previous work, we reported a single-atom-layer Pt catalyst, ${ }^{193}$ fabricated by a low-temperature amorphizing strategy of 2D $\mathrm{PtSe}_{2}$ at a single-layer limit. This catalyst shows a fully-activated surface accessible to the HER, achieving high Pt-atom-utilization efficiency of up to $\sim 26 \mathrm{wt} \%$ and a nearly $100 \%$ current density relative to a pure Pt surface. As a comparison, the single-atom catalyst that has dispersed atomic sites is capable of nearly $100 \%$ of the utilization efficiency while suffering from the limitations of low mass-loadings (e.g., usually $5 \mathrm{wt} \%$ for Pt -based ones). Their differences can also be found in theory calculations, where the former employed H coverage to evaluate the activity of the entire surface, while the latter only considered the H binding energy at single active sites. Based on the above discussions, it is also a desirable strategy to explore "single-atom-layer" catalysis based on 2D TMDCs because nearly all the atoms at the monolayer are
accessible to catalytic reactions and are stable thermodynamically.

In summary, the activation of the TMDC basal planes can bring significant benefits to the HER. With the continuous enrichment of strategies, we anticipate that TMDCs can play a more vital role in electrochemical water splitting.

## Author contributions

Y. H. conceived and initiated the project. H. X. and Z. S. carried out the literature survey, organized all the reference data, and prepared the figures. C. G. helped discuss the HER mechanism. All authors wrote the manuscript.

## Conflicts of interest

There are no conflicts of interest to declare.

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[^0]:    ${ }^{a}$ State Key Laboratory of Chemo/Biosensing and Chemometrics, College of Chemistry and Chemical Engineering, Hunan University, Changsha 410082, P. R. China. E-mail: ymhe@hnu.edu.cn
    ${ }^{b}$ School of Electronic Engineering, Lanzhou City University, Lanzhou 730070, P. R. China
    $\dagger$ Hang Xia and Zude Shi contributed equally to this work.

